# Onsemi

### **NPN General-Purpose** Amplifier

# **MMBT5551**

#### Description

This device is designed for general-purpose high-voltage amplifiers and gas discharge display drivers.

#### Features

• This Devices is Pb-Free, Halogen Free/BFR Free and is RoHS Compliant

#### ABSOLUTE MAXIMUM RATINGS (Note 1)

Symbol	Parameter	Value	Unit
V <sub>CEO</sub>	Collector-Emitter Voltage	160	V
V <sub>CBO</sub>	Collector-Base Voltage	180	×
V <sub>EBO</sub>	Emitter-Base Voltage	6	>
Ι <sub>C</sub>	Collector Current – Continuous	600	mA
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature (Note 2)	–55 to + 150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

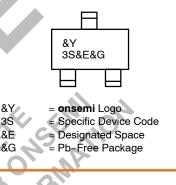
- 1. These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.
- of b, , lity of any .applications involving 2. These ratings are based on a maximum junction temperature of 150°C. These are steady-state limits. onsemi should be consulted on applications involving pulsed or low-duty cycle operations.



1. Base 2. Emitter 3. Collector

SOT-23-3 CASE 318BM

#### MARKING DIAGRAM



#### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 5 of this data sheet.

#### THERMAL CHARACTERISTICS ( $T_A = 25^{\circ}C$ unless otherwise noted) (Note 3)

Symbol	Characteristic	Мах	Unit	
PD	Total Device Dissipation	350	mW	
	Derate Above 25°C	2.8	mW/°C	
$R_{ hetaJA}$	Thermal Resistance, Junction to Ambient	357	°C/W	

#### **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted) (Note 4)

Symbol	Parameter	Test Conditions	Min	Max	Unit
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 1.0 mA, I <sub>B</sub> = 0	160		V
V <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage	$I_{\rm C} = 100 \ \mu {\rm A}, \ I_{\rm E} = 0$	180		V
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> = 10 μA, I <sub>C</sub> = 0	6.0		V
I <sub>CBO</sub>	Collector Cut–Off Current	V <sub>CB</sub> = 120 V, I <sub>E</sub> = 0		50	nA
		$V_{CB}$ = 120 V, $I_{E}$ = 0 V, $T_{A}$ = 100°C		50	μΑ
I <sub>EBO</sub>	Emitter Cut-Off Current	$V_{EB} = 4.0 \text{ V}, I_{C} = 0$		50	nA

#### **ON CHARACTERISTICS**

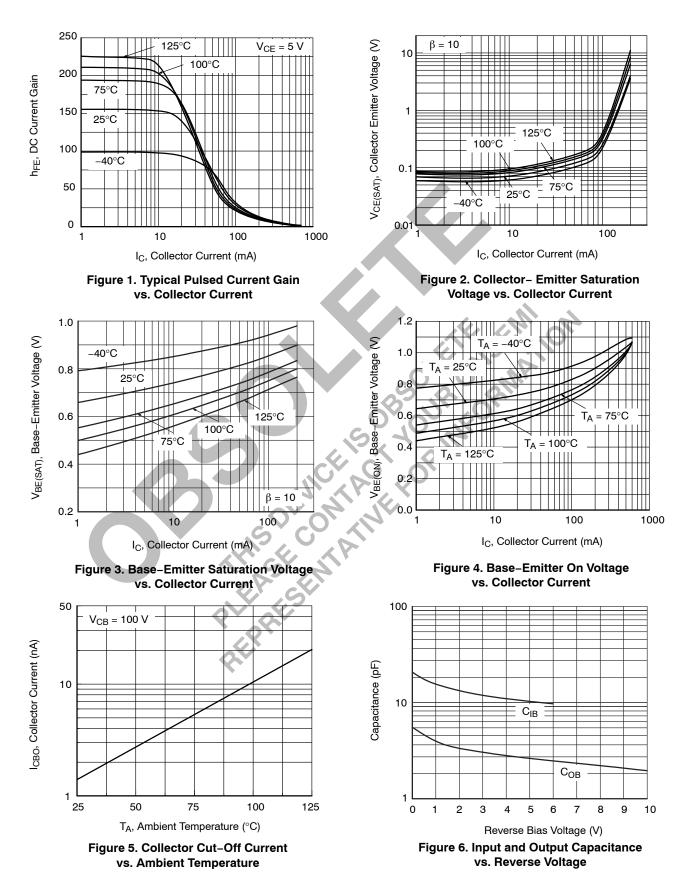
h <sub>FE</sub>	DC Current Gain	I <sub>C</sub> = 1.0 mA, V <sub>CE</sub> = 5.0 V	80		
		$I_{C}$ = 10 mA, $V_{CE}$ = 5.0 V	80	250	
		I <sub>C</sub> = 10 mA, V <sub>CE</sub> = 5.0 V (for 2N5551YBU, 2N5551YTA)	180	240	
		$I_{\rm C} = 50$ mA, $V_{\rm CE} = 5.0$ V	30		
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 10 mA, I <sub>B</sub> = 1.0 mA		0.15	V
		I <sub>C</sub> = 50 mA, I <sub>B</sub> = 5.0 mA		0.20	V
V <sub>BE(sat)</sub>	Base-Emitter On Voltage	$I_{\rm C} = 10$ mA, $I_{\rm B} = 1.0$ mA		1.0	V
		I <sub>C</sub> = 50 mA, I <sub>B</sub> = 5.0 mA		1.0	V

#### SMALL-SIGNAL CHARACTERISTICS

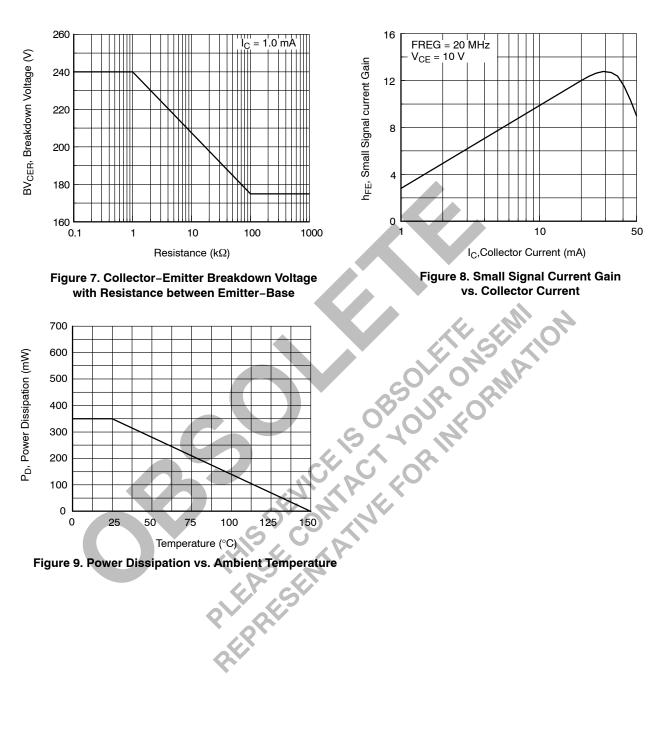
SMALL-SIGNAL CHARACTERISTICS					
f <sub>T</sub>	Current Gain Bandwidth Product	$I_{C}$ = 10 mA, $V_{CE}$ = 10 V, f = 100 MHz	100		MHz
C <sub>obo</sub>	Output Capacitance	$V_{CB} = 10 \text{ V}, I_E = 0, f = 1.0 \text{ MHz}$		6.0	pF
C <sub>ibo</sub>	Input Capacitance	V <sub>BE</sub> = 0.5 V, I <sub>C</sub> = 0, f = 1.0 MHz		20	pF
H <sub>fe</sub>	Small-Signal Current Gain	1 <sub>C</sub> = 1.0 mA, V <sub>CE</sub> = 10 V, f = 1.0 kHz	50	250	
NF	Noise Figure	I <sub>C</sub> = 250 μA, V <sub>CE</sub> = 5.0 V, R <sub>S</sub> = 1.0 kΩ, f = 10 Hz to 15.7 kHz		8.0	dB

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 3. PCB board size FR-4 76 x 114 x 0.6 T mm<sup>3</sup> (3.0 inch x 4.5 inch x 0.062 inch) with minimum land pattern size. 4. Pulse test: pulse width  $\leq$  300  $\mu$ s, duty cycle  $\leq$  2.0%.

#### **TYPICAL PERFORMANCE CHARACTERISTICS**



#### TYPICAL PERFORMANCE CHARACTERISTICS (continued)



#### **ORDERING INFORMATION** (Note 72)

Part Number	Top Mark	Package	Shipping <sup>†</sup>	
MMBT5551	3S	SOT-23-3 (Pb-Free)	3,000 / Tape & Reel	

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.



# ONSEMÍ

SOT-23 CASE 318BM **ISSUE A** DATE 01 SEP 2021 NOTES: UNLESS OTHERWISE SPECIFIED А D A) REFERENCE JEDEC REGISTRATION 3 TO-236, VARIATION AB, ISSUE H. В B) ALL DIMENSIONS ARE IN MILLIMETERS. C) DIMENSIONS ARE INCLUSIVE OF BURRS, MOLD FLASH AND TIE BAR EXTRUSIONS. D) DIMENSIONING AND TOLERANCING PER E1 ASME Y14.5M - 2009. MILLIMETERS DIM SEE DETAIL A NOM. MIN. MAX. А 1.20 2 A1 0.00 0.05 0.10 (z) A2 0.93 REF b b 0.37 0 44 0.60 е ⊕ 0.20(M) A B 0.08 0.23 с 0.15 e1 D 2.72 2.92 3.12 F Е 2.10 2.40 2.70 E1 1.15 1.30 1.50 0.95 е 0.95 BSC (A2) A1 1.90 BSC e1 0.20 L --------0.10M C  $\square$ 1.40 L1 0.55 REF С z 0.29 REF GAGE PLANE 2.20 0.25 С 1 SEATING - 1.00 PLANE - (L1) -1.90 DETAIL A LAND PATTERN SCALE: 2X RECOMMENDATION \*FOR ADDITIONAL INFORMATION ON OUR PB-FREE STRATEGY AND SOLDERING GENERIC DETAILS, PLEASE DOWNLOAD THE ON **MARKING DIAGRAM\*** SEMICONDUCTOR SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERRM/D. XXXM-. \*This information is generic. Please refer to device data sheet for actual part marking. XXX = Specific Device Code Pb-Free indicator, "G" or microdot "•", may Μ = Date Code or may not be present. Some products may = Pb-Free Package not follow the Generic Marking. Electronic versions are uncontrolled except when accessed directly from the Document Repository. **DOCUMENT NUMBER:** 98AON13784G Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. **DESCRIPTION:** SOT-23 PAGE 1 OF 1

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